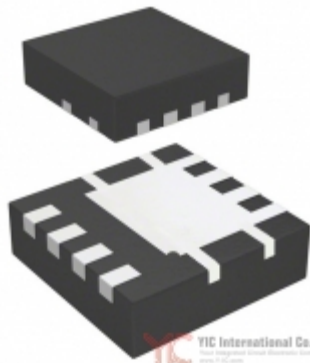


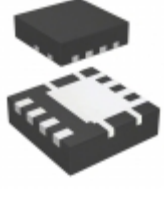


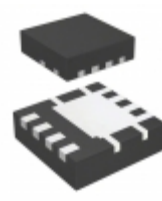
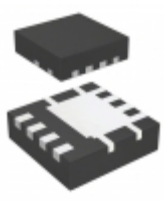

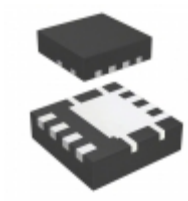
	DMN10H120SFG-7	
	Hersteller-Teilenummer:	DMN10H120SFG-7
	Hersteller / Marke:	Diodes Incorporated
	Teil der Beschreibung:	MOSFET N-CH 100V 3.8A POWERDI
	Datenblätter:	 DMN10H120SFG-7.pdf
	RoHs Status:	Bleifrei / RoHS-konform
	Lagerzustand:	New original, 1395 pcs Stock Available.
	Liefern von:	Hong Kong
	Versandweg:	DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.		

Spezifikationen

Teilenummer	DMN10H120SFG-7
Hersteller	Diodes Incorporated
Beschreibung	MOSFET N-CH 100V 3.8A POWERDI
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	1395 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerWDFN
Supplier Device-Gehäuse	PowerDI3333-8
Verlustleistung (max)	1W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	3.8A (Ta)
Rds On (Max) @ Id, Vgs	110 mOhm @ 3.3A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	10.6nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	549pF @ 50V
Antriebsspannung (Max Rds On, Min Rds On)	6V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)



















































DMN10H120SFG-7 ist neu im Original, Suche DMN10H120SFG-7 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie DMN10H120SFG-7 Diodes Incorporated mit Garantie und Vertrauen. Anfrage DMN10H120SFG-7: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>DMN10H120SFG DIODES DMN10H120SFG DIODES</p>	 <p>DMN10H120SFG-13 Diodes Incorporated MOSFET N-CH 100V 3.8A POWERDI</p>	 <p>DMN10H170SFDE-7 Displaytech MOSFET N-CH 100V 2.9A 6UDFN</p>	 <p>DMN10H170SFDE-13 Diodes Incorporated MOSFET N-CH 100V 2.9A 6UDFN</p>
 <p>DMN10H170SFG-13 Diodes Incorporated MOSFET N-CH 100V 2.9A POWERDI</p>	 <p>DMN10H120SFG-7 Displaytech MOSFET N-CH 100V 3.8A POWERDI</p>	 <p>DMN10H170SFDE-7 Diodes Incorporated MOSFET N-CH 100V 2.9A 6UDFN</p>	 <p>DMN10H120SFG-13 Displaytech MOSFET N-CH 100V 3.8A POWERDI</p>

heiße Teile

Mehr

 DMN100-7	 DMN100-7-F	 DMN1004UFV	 DMN1016UCB6	 DMN1019UFDE-7
 DMN1019USN-7	 DMN1019UVT-7	 DMN1025UFDB-7	 DMN1032UCB4	 DMN1032UCB4-7
 DMN1033UCB4	 DMN1053UCP4	 DMN1054UCB4	 DMN1054UCB4-7	 DMN10H099SFGQ-13
 DMN10H099SK3	 DMN10H099SK3-13	 DMN10H100SK3	 DMN10H120SE	 DMN10H120SE-13
 DMN10H120SFG	 DMN10H120SFG-7	 DMN10H170SFDE	 DMN10H170SFDE-7	 DMN10H170SFDE-7
 DMN10H170SK3	 DMN10H170SK3-13-79	 DMN10H170SVT-7	 DMN10H170SVTQ-7	 DMN10H220L-7
 DMN10H220LE	 DMN10H220LE-13	 DMN10H220LQ	 DMN10H220LQ-7	 DMN10H220LVT-7
 DMN10H700S	 DMN10H700S-7	 DMN1150UFB-7B	 DMN13H1750S-7	 DMN13H750S-7
 DMN15H310SE-13	 DMN2004DMK	 DMN2004DMK-7	 DMN2004DWK-7	 DMN2004DWK-7-F
 DMN2004K-7	 DMN2004K-7-F	 DMN2004TK-7	 DMN2004TK-7-F	 DMN2004VK

Contact us: Info@Y-IC.com

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